



#### flow PACK 2 1200 V / 150 A

#### Features

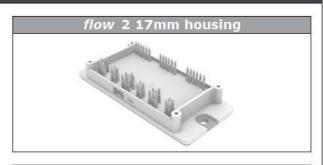
- Mitsubishi Generation 6.1 (1200V) technology for low saturation losses and improved EMC behavior
- Compact and low inductive design
- Integrated temperature sensor

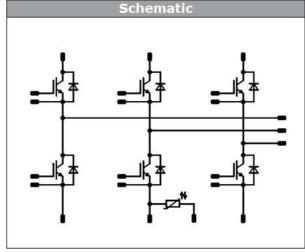
### Target applications

Industrial drives

#### Types

30-P2126PA150NB-L280F69Y





# **Maximum Ratings**

 $T_i$ =25°C, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V <sub>CES</sub>		1200	V
Collector current	Ic	$T_j = T_j \max$ $T_S = 80$ °C	158	Α
Repetitive peak collector current	$I_{CRM}$	$t_{\rm p}$ limited by $T_{ m jmax}$	300	Α
Total power dissipation	P tot	$T_j = T_j \max$ $T_S = 80$ °C	317	W
Gate-emitter voltage	V <sub>GES</sub>		±20	V
Short circuit ratings	t <sub>SC</sub> V <sub>CC</sub>	$\begin{aligned} &T_{j} \leq 150 ^{\circ}\text{C} \\ &V_{\text{GE}} = 15\text{V} \end{aligned}$	10 850	μs V
Maximum Junction Temperature	$T_{ m jmax}$		175	°C

Copyright Vincotech 1 29 May. 2015 / Revision 3



target datasheet

Parameter	Symbol	Conditions	Value	Unit
Inverter Diode				
Peak Repetitive Reverse Voltage	$V_{ m RRM}$		1200	V
Continuous (direct) forward current	I <sub>F</sub>	$T_{\rm j} = T_{\rm jmax}$ $T_{\rm h} = 80 ^{\circ} {\rm C}$	119	А
Repetitive peak forward current	$I_{\mathrm{FRM}}$		300	А
Total power dissipation	P tot	$T_{\rm j} = T_{\rm jmax}$ $T_{\rm h} = 80 ^{\circ} {\rm C}$	202	w
Maximum Junction Temperature	$T_{ m jmax}$		175	°C

## **Module Properties**

Parameter	Symbol	Conditions	6	Value	Unit
Thermal Properties					
Storage temperature	T <sub>stg</sub>			-40+125	°C
Operation Junction Temperature	$T_{\rm jop}$			-40+(T <sub>jmax</sub> - 25)	°C
					•
Isolation Properties					
Isolation voltage	$V_{isol}$	DC voltage	t <sub>p</sub> =2s	4000	v
Creepage distance				min 12,7	mm
Clearance				min 12,7	mm
Comparative Tracking Index	СТІ			>200	



target datasheet

## **Characteristic Values**

### **Inverter Switch**

Parameter	Symbol		Cone	ditions				Value		Unit
			<i>V</i> <sub>GE</sub> [ <b>V</b> ]	$V_{CE}[V]$	I <sub>c</sub> [A]	<i>T</i> <sub>j</sub> [ °C]	Min	Тур	Max	
Static	-									
Gate-emitter threshold voltage	V <sub>GE(th)</sub>	V <sub>GE</sub> =V <sub>CE</sub>			0,015	25 125	5,4	6	6,6	V
Collector-emitter saturation voltage	$V_{CEsat}$		15		150	25 125 150		1,70 1,90 1,95	2,15	V
Collector-emitter cut-off current	I <sub>CES</sub>		0	1200		25 125			520	μΑ
Gate-emitter leakage current	$I_{GES}$		20	0		25 125			1000	nA
Internal gate resistance	rg							none		Ω
Input capacitance	C <sub>ies</sub>							-	15000	
Output capacitance	C oes	f=100KHz	0	10		25		-	3000	pF
Reverse transfer capacitance	Cres							-	260	
Gate charge	Qg		15	600	150	25		315		nC
Thermal										
Thermal resistance junction to sink	$R_{ ext{th(j-s)}}$	Phase-Change Material λ=3,4W/mK						0,3		K/W

## **Inverter Diode**

Parameter	Symbol		Cond	litions				Value		Unit
				$v_{\rm r}[V]$	<i>I</i> <sub>F</sub> [A]	T <sub>j</sub> [°C]	Min	Тур	Max	
Static										
						25		2,50	3,3	
Forward voltage	$V_{\rm F}$				150	125		2,06		V
						150		2,00		
Reverse leakage current	,			1200		25			50	
Reverse leakage current	$I_{\mathbf{r}}$			1200		150			-	μΑ
Thermal										
Thermal resistance junction to sink		Phase-Change Material λ=3,4W/mK						0,47		K/W



target datasheet

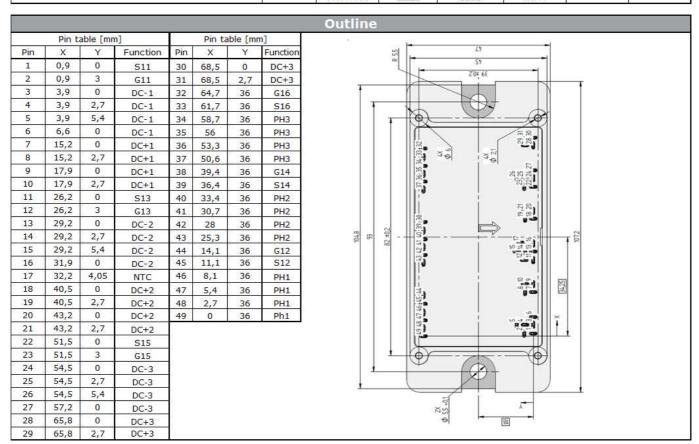
# **Thermistor**

Parameter	Symbol		Con	ditions				Value		Unit
			<i>V</i> <sub>GE</sub> [V]	$V_{CE}[V]$	$I_{C}[A]$	<i>T</i> <sub>j</sub> [ °C]	Min	Тур	Max	
			_							
Rated resistance	R					25		22		kΩ
Deviation of R100	$\Delta_{R/R}$	R100=1486 Ω				100	-12		+12	%
Power dissipation	P					25		200		mW
Power dissipation constant						25		2		mW/K
B-value	B <sub>(25/50)</sub>	Tol. ±3%				25		3950		К
B-value	B <sub>(25/100)</sub>	Tol. ±3%				25		3998		К
Vincotech NTC Reference									В	



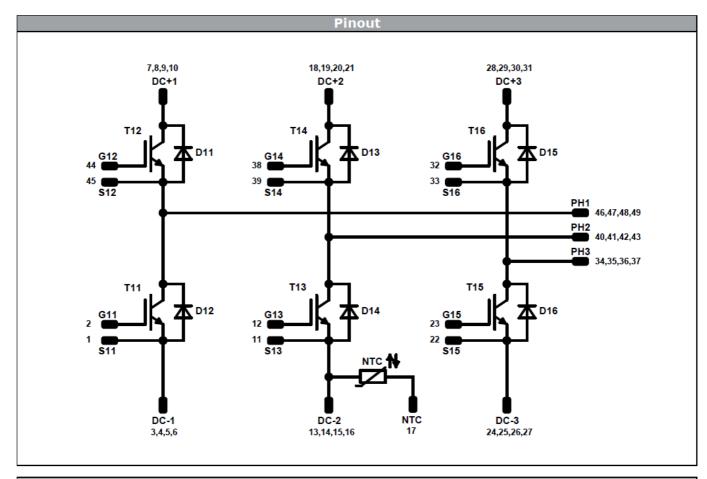
target datasheet

		Ordering	g Code &	Marking	)			
Version	Ordering Code		in DataN	Matrix as	in packagin	g barcode as		
without thermal paste 17mm housing	30-P2126PA150NB-L280F69Y			L280	F69Y	L280F69Y		
with thermal paste 17mm housing	30-P2126PA150NB-L280F69Y-/3/			L280	F69Y	L280F69Y L280F69Y-/3/		
		1	N-	me	Date code	UL & Vinco	Let	Serial
NN-NNNNNNNNNNNNNNNNNNNNNNNNNNNNNNNNNNN		Text -		INNN-NNNNNN	WWYY	UL Vinco	LLLLL	SSSS
Vinco LLLLL SSSS		Datamatrix	Type&Ver	Lot number	Serial	Date code		
NA NA 100 100 1	titled 105 med	Datamatrix	TTTTTTTVV	LLLLL	SSSS	WWYY		





target datasheet



	<b>I</b> dentification								
ID	Component	Voltage	Current	Function	Comment				
T11,T12,T13 T14,T15,T16	IGBT	1200V	150A	Inverter Switch	2*CH0075C-1200S002				
D11,D12,D13 D14,D15,D16	FWD	1200V	150A	Inverter Diode	CH0150R-1200S001				
NTC	NTC	-	-	Thermistor					



target datasheet

		Packaging instruction			-	
Standard packaging quantity (SPQ)	42		>SPQ	Standard	<spq< td=""><td>Sample</td></spq<>	Sample

Handling instruction
Handling instructions for flow 2 packages see vincotech.com website.

Document No.:	Date:	Modification:	Pages
30-P2126PA150NB-L280F69Y-T3-14	29 May. 2015		

Product status definition						
Datasheet Status	Product Status	Definition				
Target	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. The data contained is exclusively intended for technically trained staff.				

#### DISCLAIMER

The information, specifications, procedures, methods and recommendations herein (together "information") are presented by Vincotech to reader in good faith, are believed to be accurate and reliable, but may well be incomplete and/or not applicable to all conditions or situations that may exist or occur. Vincotech reserves the right to make any changes without further notice to any products to improve reliability, function or design. No representation, guarantee or warranty is made to reader as to the accuracy, reliability or completeness of said information or that the application or use of any of the same will avoid hazards, accidents, losses, damages or injury of any kind to persons or property or that the same will not infringe third parties rights or give desired results. It is reader's sole responsibility to test and determine the suitability of the information and the product for reader's intended use.

#### LIFE SUPPORT POLICY

Vincotech products are not authorised for use as critical components in life support devices or systems without the express written approval of Vincotech.

#### As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

Copyright Vincotech 7 29 May. 2015 / Revision 3